Thyristor/Thyristor Thyristor/Diode

SCA200AA, SCE200AA

IT(AV) = 200A, VRRM = 800 - 1800V

SanRex Thyristor/Thyristor (SCA series), Thyristor/Diode (SCE series) are designed for general purpose high voltage applications. The modules are an Isolated Industrial Standard Package.

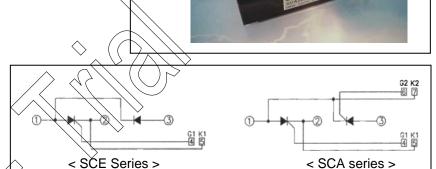
Features

- * Glass-passivated Junctions Feature
- * High Surge Current (ITSM=6500A)
- * Low On-State Voltage Drop (VTM=1.4V)
- * UL E76102 approved
- * RoHS compliance

Typical Applications

- * Welders
- * Uninterruptible Power Supplies (UPS)/
- * Temperature and Lighting Controls
- * Soft Starters
- * Battery Chargers

< Maximum Ratings >



Internal schematic diagram

Ti = 25°C (unless otherwise noted) per diode

Symbol	<	Item	Ratings				
			SCA200AA80 SCE200AA80	SCA200AA120 SCE200AA120	SCA200A SCE200A		Unit
V_{RRM}	Repetitive Pe	eak Reverse Voltage	800	1200	1600	1800	V
V_{RSM}	Non-Repetiti	ve Peak Reverse Voltage	960	1300	1700	1900	V
V_{DRM}	Repetitive Pe	eak Off-state Voltage	800	1200	1600	1800	V
I _{T(AV)}	Average On-	Average On-state Current T _C = 82°C				200	А
I _{T(RMS)}	R.M.S. On-st	ate Current	T _C = 82°C	c = 82°C 314			А
I _{TSM}	Surge On-state Current		1/2 cycle, 50Hz/60Hz, Peak value, Non-repetitive			6000/6500	А
l²t	I ² t (for fusing	g)	Value for one cycle surge current			180000	A^2 s
P_{GM}	Peak Gate Power Dissipation					10	W
$P_{G(AV)}$	Average Gate Power Dissipation					3	W
I _{FGM}	Peak Gate Current					3	Α
V_{FGM}	Peak Gate Voltage (Forward)					10	V
V_{RGM}	Peak Gate Voltage (Reverse)					5	V
di/dt	Critical Rate of Rise of On-state Current		$I_{G}=100$ mA, $V_{D}=1/2V_{DRM}$, dig/dt=0.1A/F s			200	A/Fs
V _{ISO}	Isolation Breakdown Voltage		A.C. 1 minute			3000	
Tj	Operating Junction Temperature					-40 to +125	°C
T _{stg}	Storage Temperature					-40 to +125	°C
	Mounting Torque	Mounting M6	Recommende	d Value 2.5 to 3.9)	4.7	N*m
		Terminals M6	Recommende	d Value 2.5 to 3.9)	4.7	
	Mass		Typical Value			210	g

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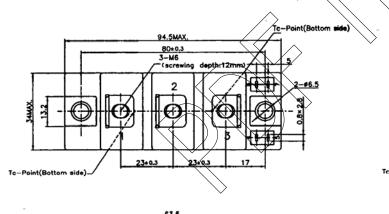
Thyristor/Thyristor, Thyristor/Diode Module

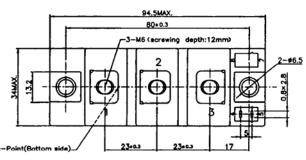
SCA200AA, SCE200AA series

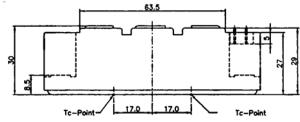
< Electrical Characteristics >

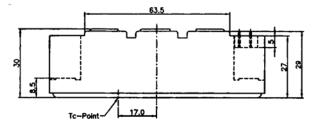
Tj= 25°C (unless otherwise noted) per diode

Symbol	Item	Conditions	Ratings	Unit	
I _{DRM}	Repetitive Peak Off-state Current	$T_i = 125^{\circ}C, V_D = V_{DRM}$	100	mA	
I _{RRM}	Repetitive Peak Reverse Current	$T_j = 125$ °C, $V_R = V_{RRM}$	100	mA	
V_{TM}	Peak On-State Voltage	I _T = 600A	1.4	V	
VT(T0)	Threshold Voltage	T _j = 25°C	1.0	V	
	Threshold Voltage	T _j = 125°C	0.85	V	
rt	Slone Periotones	T _j = 25°C	0.8	M Ohm	
	Slope Resistance	T _j = 125°C	1.1		
I _{GT}	Gate Trigger Current	VD=6V, IT=1A	100	mA	
V _{GT}	Gate Trigger Voltage	VD=6V, IT=1A	3	V	
V_{GD}	Non-Trigger Gate Voltage	$Tj = 125^{\circ}C, V_D = 1/2V_{DRM}$	0.25	V	
dv/dt	Critical Rate of Rise of Off-state Voltage	$Tj = 125^{\circ}C, V_D = 2/3V_{DRM}$	1000	V/Fs	
Rth(j-c)	Thermal Resistance	Junction to case	0.155	°C/W	









< SCA series : Thyristor/Thyristor >

< SCE series : Thyristor/Diode >

* Dimensions in millimeters (1mm=0.0394")